



## -30V/-10A P-Channel Enhancement Mode MOSFET

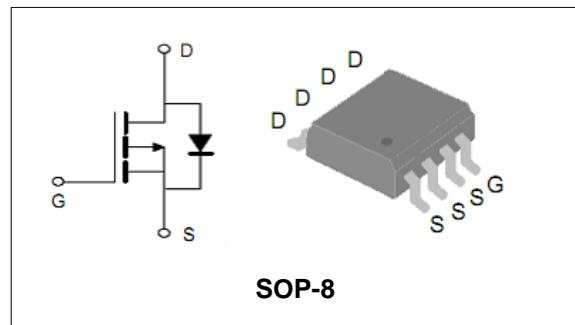
## Features

- -5V Logic Level Control
- Dual P-Channel SOP8 Package

BVDSS	-30	V
ID	-10	A
RDS(on)@VGS=-4.5V	22	mΩ
RDS(on)@VGS=-10V	17	mΩ

## Applications

- PWM applications
- Load switch
- Power management



## Order Information

Product	Package	Marking	Reel Size	Reel	Carton
PTS30P10	SOP-8	PTS30P10	13inch	3000PCS	48000PCS

## Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit	
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	-30	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
T <sub>J</sub>	Maximum Junction Temperature	150	°C	
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	°C	
I <sub>S</sub>	Diode Continuous Forward Current	TA =25°C	-10	A
<b>Mounted on Large Heat Sink</b>				
I <sub>DM</sub>	Pulse Drain Current Tested (Sillicon Limit) (Note1)	TA =25°C	-50	A
I <sub>D</sub>	Continuous Drain current	TA =25°C	-10	A
P <sub>D</sub>	Maximum Power Dissipation	TA =25°C	1.5	W
R <sub>θJA</sub>	Thermal Resistance Junction-to-Ambient (Note2)		83	°C/W



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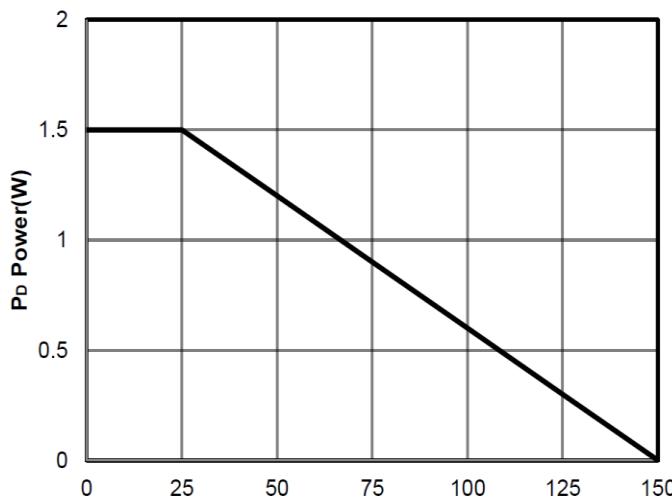
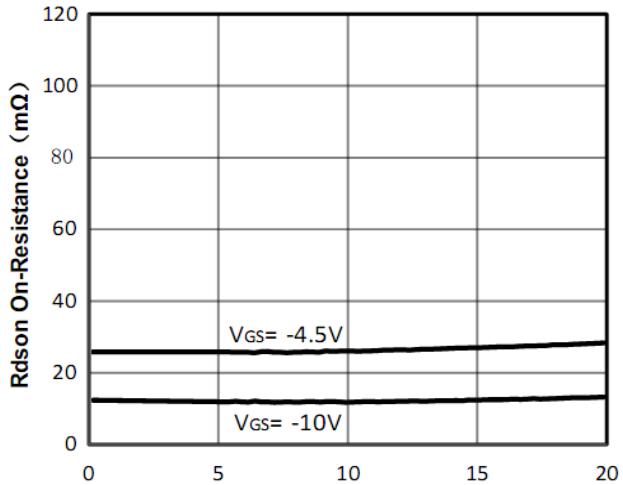
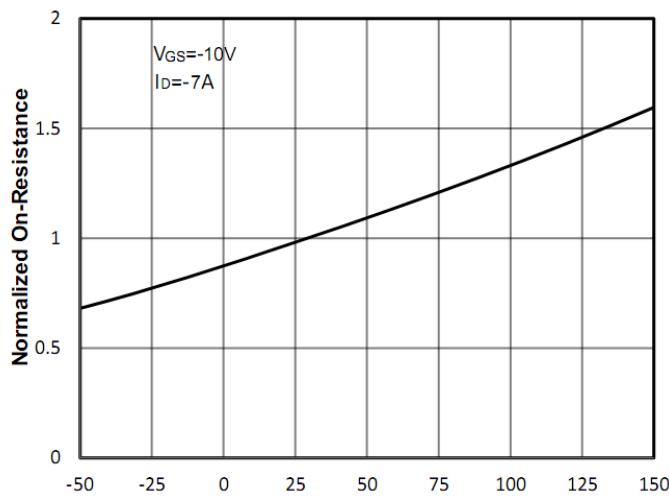
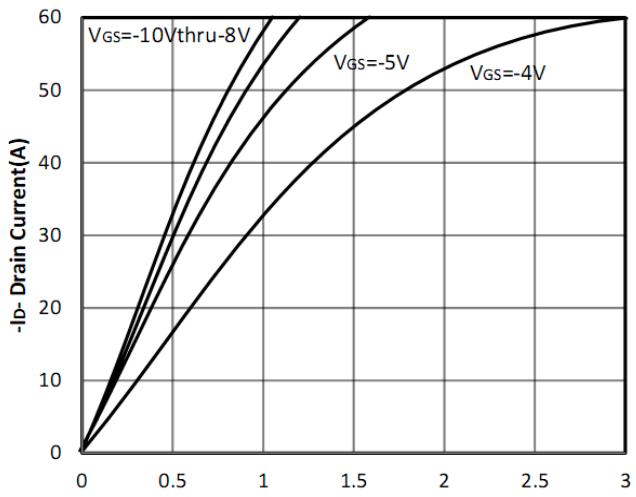
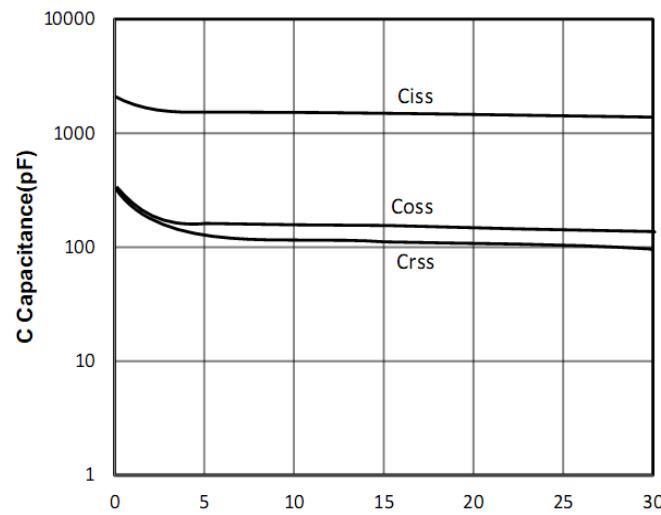
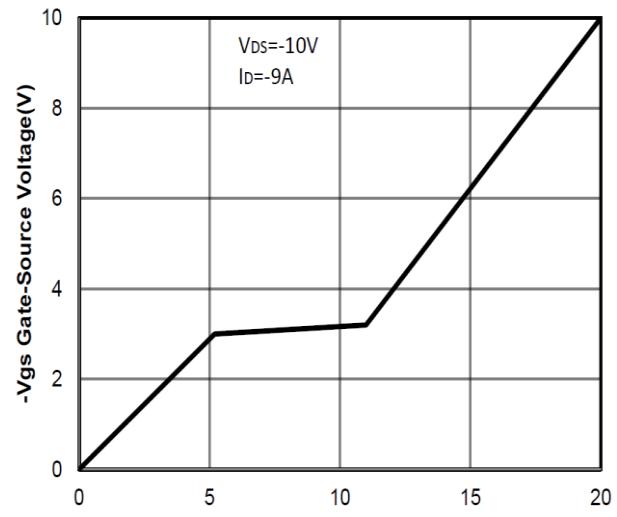
Symbol	Parameter	Condition	Min.	Typ.	Max.	Unit
<b>Static Electrical Characteristics @ <math>T_J = 25^\circ C</math> (unless otherwise stated)</b>						
$V_{(BR)DSS}$	Drain- Source Breakdown Voltage	$V_{GS}=0V, ID=-250\mu A$	-30	--	--	V
$I_{DSS}$	Zero Gate Voltage Drain current	$V_{DS}=-30V, V_{GS}=0V$	--	--	-1	$\mu A$
$I_{GSS}$	Gate-Body Leakage Current	$V_{GS}=\pm 20V, V_{DS}=0V$	--	--	$\pm 100$	nA
$V_{GS(TH)}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, ID=-250\mu A$	-1	-1.5	-2.5	V
$R_{DS(ON)}$	Drain-Source On-State Resistance (Note3)	$V_{GS}=-10V, ID=-7A$	--	17	23	$m\Omega$
		$V_{GS}=-4.5V, ID=-5A$	--	22	34	$m\Omega$
<b>Dynamic Electrical Characteristics @ <math>T_J = 25^\circ C</math> (unless otherwise stated) (Note4)</b>						
$C_{iss}$	Input Capacitance	$V_{DS}=-15V,$ $V_{GS}=0V,$ $F=1MHz$	--	1500	--	pF
$C_{oss}$	Output Capacitance		--	178	--	pF
$C_{rss}$	Reverse Transfer Capacitance		--	146	--	pF
$Q_g$	Total Gate Charge	$V_{DS}=-15V,$ $ID=-6A,$ $V_{GS}=-10V$	--	28.7	--	nC
$Q_{gs}$	Gate-Source Charge		--	5.5	--	nC
$Q_{gd}$	Gate-Drain Charge		--	5.4	--	nC
<b>Switching Characteristics (Note4)</b>						
$t_{d(on)}$	Turn-on Delay Time	$V_{DD}=-15V,$ $ID=-6A,$ $RG=2.5\Omega,$ $V_{GS}=-10V$	--	10	--	nS
$t_r$	Turn-on Rise Time		--	44	--	nS
$t_{d(off)}$	Turn-off Delay Time		--	54	--	nS
$t_f$	Turn-off Fall Time		--	59	--	nS
<b>Source- Drain Diode Characteristics@ <math>T_J = 25^\circ C</math> (unless otherwise stated)</b>						
$V_{SD}$	Forward on voltage	$IS=-10A, V_{GS}=0V$	--	--	-1.2	V

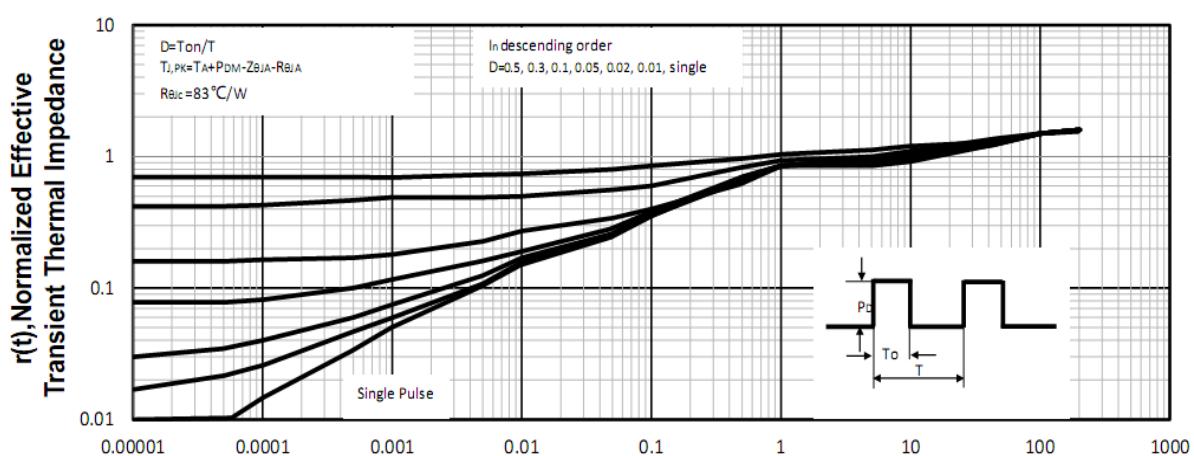
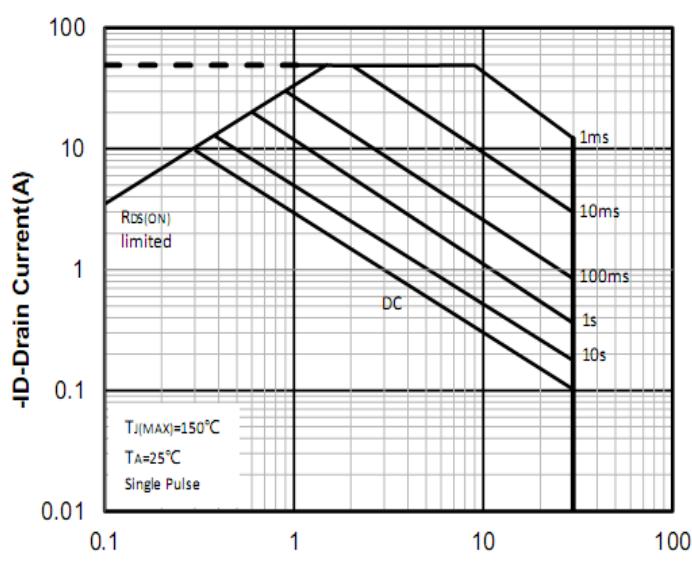
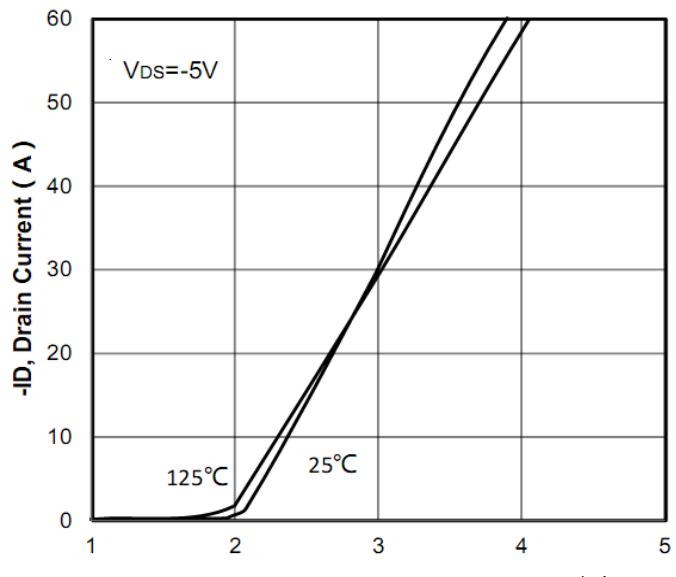
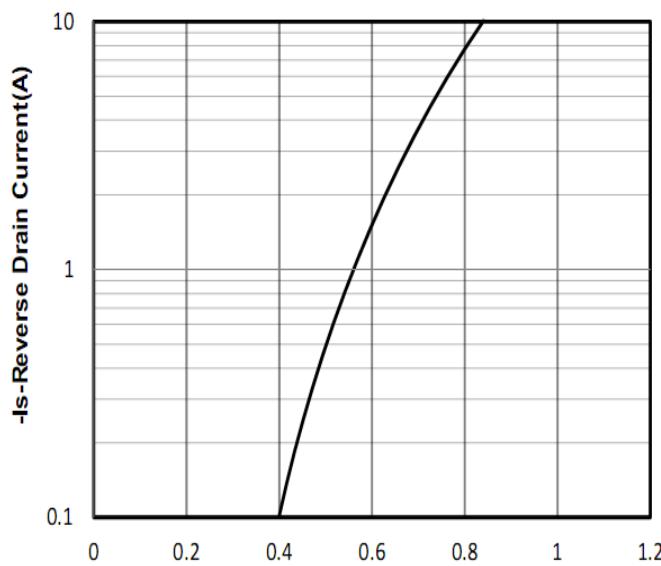
Note:

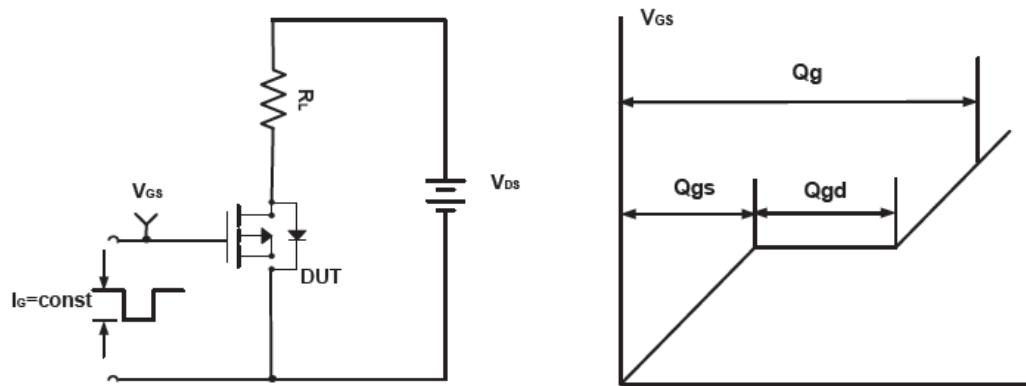
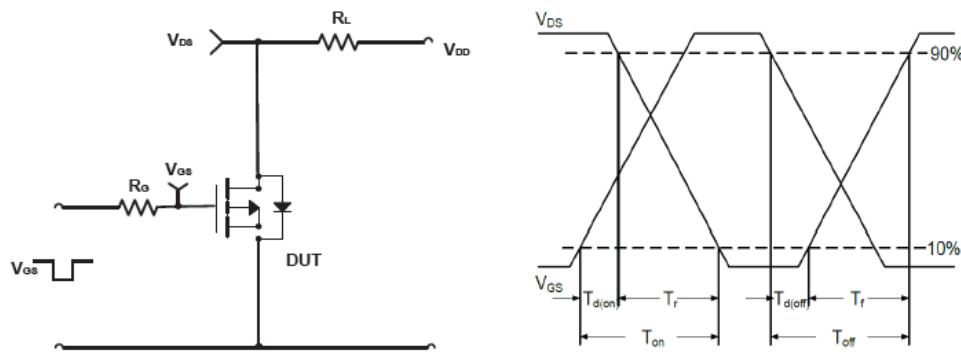
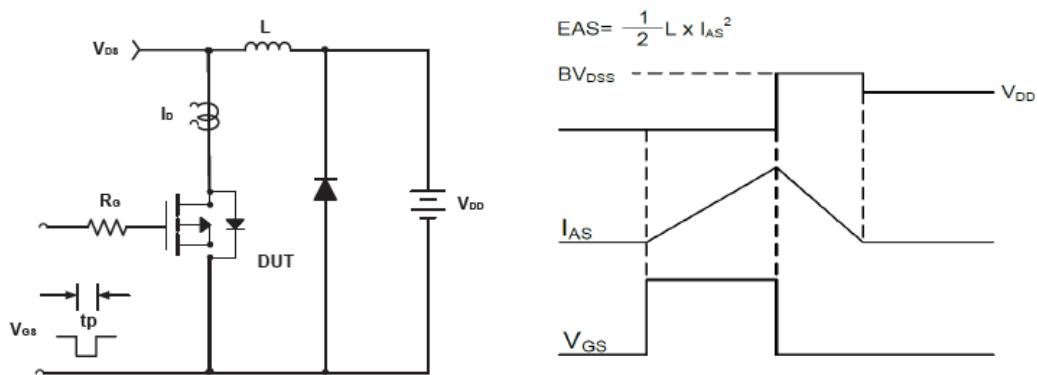
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board,  $t \leq 10$  sec
3. Pulse Test: pulse width  $\leq 300$  us, duty cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production testing.

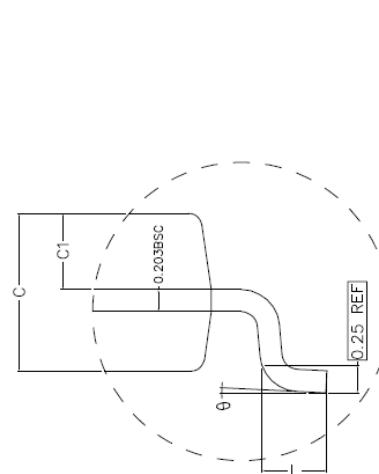
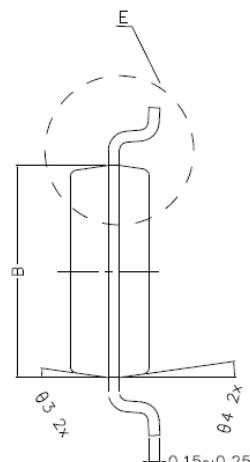
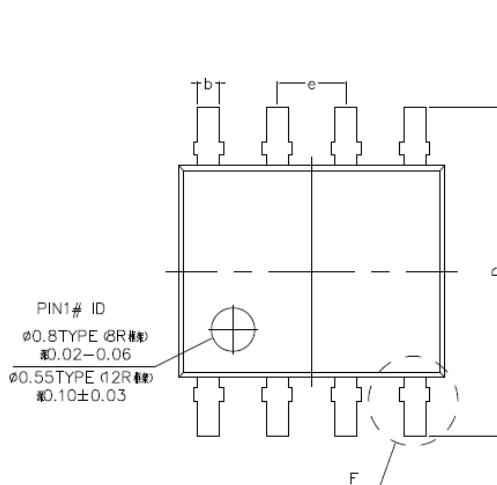
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## Typical Characteristics

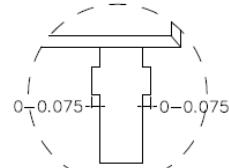
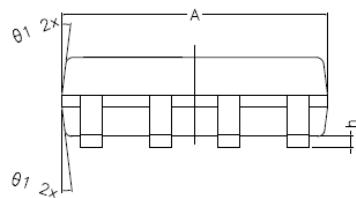
Figure 1:  $T_J$  Junction Temperature (°C)Figure 2:  $-I_D$  Drain Current (A)Figure 3:  $T_J$  Junction Temperature (°C)Figure 4:  $-V_{DS}$  Drain-Source Voltage (V)Figure 5:  $-V_{DS}$  Drain-Source Voltage (V)Figure 6:  $-Q_G$  Gate Charge (nC)

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**Test Circuit and Waveform:**

**Figure A Gate Charge Test Circuit & Waveforms**

**Figure B Switching Test Circuit & Waveforms**

**Figure C Unclamped Inductive Switching Circuit & Waveforms**

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**SOP-8 Package Outline Dimensions (Units: mm)**


DETAIL E



DETAIL F

COMMON DIMENSIONS (UNITS OF MEASURE IS mm)			
	MIN	NORMAL	MAX
A	4.800	4.900	5.000
B	3.800	3.900	4.000
C	1.350	1.450	1.550
C1	0.650	0.700	0.750
D	5.900	6.100	6.300
L	0.500	0.600	0.700
b	0.350	0.400	0.450
h	0.050	0.150	0.250
e	1.270 TYPE		
$\theta_1$	7° TYPE(8R)	12° TYPE(12R)	
$\theta_2$	7° TYPE(8R)	10° TYPE(12R)	
$\theta_3$	8° TYPE(8R)	12° TYPE(12R)	
$\theta_4$	8° TYPE(8R)	10° TYPE(12R)	
$\theta$	$0^\circ \sim 8^\circ$		